

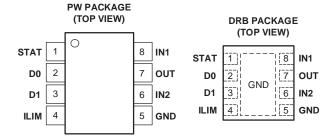
# **AUTOSWITCHING POWER MUX**

#### **FEATURES**

- Two-Input, One-Output Power Multiplexer With Low r<sub>DS(on)</sub> Switches:
  - 84 m $\Omega$  Typ (TPS2115A)
  - 120 m $\Omega$  Typ (TPS2114A)
- Reverse and Cross-Conduction Blocking
- Wide Operating Voltage Range . . . . 2.8 V to 5.5 V
- Low Standby Current . . . . 0.5-μA Typ
- Low Operating Current . . . . 55-μA Typ
- Adjustable Current Limit
- Controlled Output Voltage Transition Times, Limits Inrush Current and Minimizes Output Voltage Hold-Up Capacitance
- CMOS- and TTL-Compatible Control Inputs
- Manual and Auto-Switching Operating Modes
- Thermal Shutdown
- Available in TSSOP-8 and 3mm x 3mm SON-8 Packages

#### **APPLICATIONS**

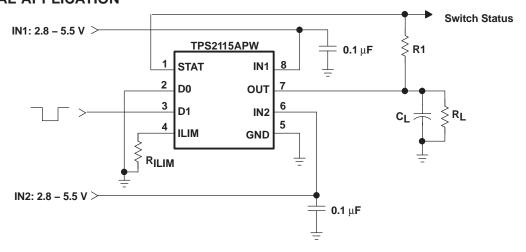
- PCs
- PDAs
- Digital Cameras
- Modems
- Cell Phones
- Digital Radios
- MP3 Players



#### **DESCRIPTION**

The TPS211xA family of power multiplexers enables seamless transition between two power supplies, such as a battery and a wall adapter, each operating at 2.8–5.5 V and delivering up to 1 A. The TPS211xA family includes extensive protection circuitry, including user-programmable current limiting, thermal protection, inrush current control, seamless supply transition, cross-conduction blocking, and reverse-conduction blocking. These features greatly simplify designing power multiplexer applications.

# **TYPICAL APPLICATION**



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### **AVAILABLE OPTIONS**

FEAT	TURE	TPS2114A	TPS2115A
Current Limit Adjustment Range		0.31-0.75A	0.63-1.25A
Manual Manual		Yes	Yes
Switching Modes	Automatic	Yes	Yes
Switch Status Output	·	Yes	Yes
Dealeana		TCCOD 0	TSSOP-8
Package		TSSOP-8	SON-8

#### **ORDERING INFORMATION**

TA	PACKAGE	ORDERING NUMBER(1)	MARKINGS
	TSSOD 8 (DW)	TPS2114APW	2114A
-40°C to 85°C	TSSOP-8 (PW)	TPS2115APW	2115A
	SON-8 (DRB)	TPS2115ADRB	2115A

<sup>(1)</sup> The PW package is available taped and reeled. Add an R suffix to the device type (e.g., TPS2114APWR) to indicate tape and reel.

#### **PACKAGE DISSIPATION RATINGS**

PACKAGE	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> ≤ 25°C POWER RATING	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
TSSOP-8 (PW)	3.9 mW/°C	387 mW	213 mW	155 mW
SON-8 (DRB)	25.0 mW/°C	2.50 W	1.38 W	1.0 W

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted(1)

		TPS2114A, TPS2115A
Input voltage range at pins IN1, IN2, D0	, D1, ILIM(2)	−0.3 V to 6 V
Output voltage range, VO(OUT), VO(ST	TAT) <sup>(2)</sup>	−0.3 V to 6 V
Output sink current, IO(STAT)		5 mA
Continuous sutput surrent la	TPS2114A	0.9 A
Continuous output current, IO	TPS2115A	1.5 A
Continuous total power dissipation		See Dissipation Rating Table
Operating virtual junction temperature ra	ange, TJ	-40°C to 125°C
Storage temperature range, T <sub>stg</sub>		−65°C to 150°C
Lead temperature soldering 1,6 mm (1/	16 inch) from case for 10 seconds	260°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# **RECOMMENDED OPERATING CONDITIONS**

		MIN	MAX	UNIT
Innut voltage at INIA Varia	V <sub>I(IN2)</sub> ≥ 2.8 V	1.5	5.5	V
Input voltage at IN1, V <sub>I(IN1)</sub>	V <sub>I(IN2)</sub> < 2.8 V	2.8	5.5	V
Input voltage at INO Varia	V <sub>I(IN1)</sub> ≥ 2.8 V	1.5	5.5	V
Input voltage at IN2, V <sub>I(IN2)</sub>	V <sub>I(IN2)</sub> < 2.8 V	2.8	5.5	\ \
Input voltage, V <sub>I(DO)</sub> , V <sub>I(D1)</sub>		0	5.5	V
Command limit adjustment many Lawrence	TPS2114A	0.31	0.75	
urrent limit adjustment range, IO(OUT)	TPS2115A	0.63	1.25	A
Operating virtual junction temperature, TJ	•	-40	125	°C

<sup>(2)</sup> All voltages are with respect to GND.



# **ELECTROSTATIC DISCHARGE (ESD) PROTECTION**

	MIN	MAX	UNIT
Human body model		2	kV
CDM		500	V

# **ELECTRICAL CHARACTERISTICS**

over recommended operating junction temperature range,  $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$ ,  $R_{ILIM} = 400 \Omega$  (unless otherwise noted)

PARAMETER		TECT			TPS2114A		TPS2115A			LINUT
		TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
POWER S	WITCH									
	Drain-source on-state resistance (INx–OUT)	T <sub>J</sub> = 25°C, I <sub>L</sub> = 500 mA	$V_{I(IN1)} = V_{I(IN2)} = 5.0 \text{ V}$		120	140		84	110	
			$V_{I(IN1)} = V_{I(IN2)} = 3.3 \text{ V}$		120	140		84	110	$m\Omega$
r= a(1)			$V_{I(IN1)} = V_{I(IN2)} = 2.8 \text{ V}$		120	140		84	110	
r <sub>DS(on)</sub> (1)		T <sub>J</sub> = 125°C, I <sub>L</sub> = 500 mA	$V_{I(IN1)} = V_{I(IN2)} = 5.0 \text{ V}$			220			150	
			$V_{I(IN1)} = V_{I(IN2)} = 3.3 \text{ V}$			220			150	$\text{m}\Omega$
			$V_{I(IN1)} = V_{I(IN2)} = 2.8 \text{ V}$			220			150	

<sup>(1)</sup> The TPS211xA can switch a voltage as low as 1.5 V as long as there is a minimum of 2.8 V at one of the input power pins. In this specific case, the lower supply voltage has no effect on the IN1 and IN2 switch on-resistances.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
LOGIC INPUTS (D0 AND D1)						
V <sub>IH</sub> High-level input voltage		2			V	
V <sub>IL</sub> Low-level input voltage				0.7	V	
	D0 or D1 = High, sink current			1		
Input current at D0 or D1	D0 or D1 = Low, source current	0.5	1.4	5	μΑ	
SUPPLY AND LEAKAGE CURRENTS	3					
	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)} = 5.5 \text{ V}$ , $V_{I(IN2)} = 3.3 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$		55	90		
	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)} = 3.3 \text{ V}$ , $V_{I(IN2)} = 5.5 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$		1	12		
Supply current from IN1 (operating)	D0 = D1 = Low (IN2 active), V <sub>I(IN1)</sub> = 5.5 V, V <sub>I(IN2)</sub> = 3.3 V, I <sub>O(OUT)</sub> = 0 A			75	μΑ	
	D0 = D1 = Low (IN2 active), $V_{I(IN1)} = 3.3 \text{ V}$ , $V_{I(IN2)} = 5.5 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$			1 1 75 1 12		
	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)} = 5.5 \text{ V}$ , $V_{I(IN2)} = 3.3 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$			1		
0 1 (1) (1) (1)	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)} = 3.3 \text{ V}$ , $V_{I(IN2)} = 5.5 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$			75		
Supply current from IN2 (operating)	D0 = D1 = Low (IN2 active), $V_{I(IN1)} = 5.5 \text{ V}$ , $V_{I(IN2)} = 3.3 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$		1	12	μΑ	
	D0 = D1 = Low (IN2 active), V <sub>I(IN1)</sub> = 3.3 V, V <sub>I(IN2)</sub> = 5.5 V, I <sub>O(OUT)</sub> = 0 A		55	90		
Quiescent current from IN1	D0 = D1 = High (inactive), $V_{I(IN1)} = 5.5 \text{ V}$ , $V_{I(IN2)} = 3.3 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$		0.5	2		
(STANDBY)	D0 = D1 = High (inactive), $V_{I(IN1)} = 3.3 \text{ V}$ , $V_{I(IN2)} = 5.5 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$			1	μΑ	
Quiescent current from IN2	$D0 = D1 = High (inactive), V_{I(IN1)} = 5.5 \text{ V}, V_{I(IN2)} = 3.3 \text{ V}, I_{O(OUT)} = 0 \text{ A}$			1		
(STANDBY)	D0 = D1 = High (inactive), $V_{I(IN1)} = 3.3 \text{ V}$ , $V_{I(IN2)} = 5.5 \text{ V}$ , $I_{O(OUT)} = 0 \text{ A}$	V, I <sub>O(OUT)</sub> = 0 A	2	μΑ		
Forward leakage current from IN1 (measured from OUT to GND)	D0 = D1 = High (inactive), $V_{I(IN1)}$ = 5.5 V, IN2 open, $V_{O(OUT)}$ = 0 V (shorted), $T_J$ = 25°C		0.1	5	μΑ	
Forward leakage current from IN2 (measured from OUT to GND)	D0 = D1= High (inactive), $V_{I(IN2)}$ = 5.5 V, IN1 open, $V_{O(OUT)}$ = 0 V (shorted), $T_J$ = 25°C		0.1	5	μΑ	
Reverse leakage current to INx (measured from INx to GND)	D0 = D1 = High (inactive), $V_{I(INx)} = 0 \text{ V}$ , $V_{O(OUT)} = 5.5 \text{ V}$ , $T_J = 25^{\circ}\text{C}$		0.3	5	μΑ	



ELECTRICAL CHARACTERISTICS (Continued) over recommended operating junction temperature range,  $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$ ,  $R_{ILIM} = 400 \Omega$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT		
CURRENT LIMIT CIRCUIT								
Command Parity and any	TPS2114A	R <sub>ILIM</sub> = 400 Ω	0.51	0.63	0.80			
	1P32114A	R <sub>ILIM</sub> = 700 Ω	0.30	0.36	0.50			
	Current limit accuracy	TPS2115A	R <sub>ILIM</sub> = 400 Ω	0.95	1.25	1.56	A	
		IFSZIISA	R <sub>ILIM</sub> = 700 Ω	0.47	0.71	0.99		
td	Current limit settling time(1)		Time for short-circuit output current to settle within 10% of its steady state value.		1		ms	
	Input current at ILIM		V <sub>I(ILIM)</sub> = 0 V, I <sub>O(OUT)</sub> = 0 A	-15		0	μΑ	

<sup>(1)</sup> Not tested in production.

PARAMETER	TEST CONDITION	NS MIN	TYP	MAX	UNIT
UVLO					
IN1 and IN2 UVLO IN1 and IN2 UVLO hysteresis(1) Internal V <sub>DD</sub> UVLO (the higher of IN1 and IN2) Internal V <sub>DD</sub> UVLO hysteresis(1)	Falling edge	1.15	1.25		.,
	Rising edge		1.30	1.35	V
IN1 and IN2 UVLO hysteresis <sup>(1)</sup>		30	57	65	mV
Internal V I IIV O (the literary (INIA and INIO)	Falling edge	2.4	2.53		
internal VDD UVLO (the nigher of IN1 and IN2)	Rising edge		2.58	5	V
Internal V <sub>DD</sub> UVLO hysteresis(1)		30	50	75	mV
UVLO deglitch for IN1, IN2 <sup>(1)</sup>	Falling edge		110		μs

<sup>(1)</sup> Not tested in production.

PARAMETER TEST CONDITION		TEST CONDITIONS	MIN	TYP	MAX	UNIT
REVERSE CO	NDUCTION BLOCKING					
ΔVO(I_block)	Minimum input-to-output voltage difference to block switching	D0 = D1 = high, $V_{I(INx)}$ = 3.3 V. Connect OUT to a 5 V supply through a series 1-k $\Omega$ resistor. Let D0 = low. Slowly decrease the supply voltage until OUT connects to IN1.	80	100	120	mV

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
THERMAL SHUTDOWN	·				
Thermal shutdown threshold(1)	TPS211xA is in current limit.	135			
Recovery from thermal shutdown(1)	TPS211xA is in current limit.	125			°C
Hysteresis(1)			10		
IN2-IN1 COMPARATORS	·	•			
Hysteresis of IN2–IN1 comparator		0.1		0.2	V
Deglitch of IN2–IN1 comparator (both ↑↓)(1)		10	20	50	μs

<sup>(1)</sup> Not tested in production.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STAT OUTPUT					
Leakage current	V <sub>O</sub> (STAT) = 5.5 V		0.01	1	μА
Saturation voltage	I <sub>I</sub> (STAT) = 2 mA, IN1 switch is on		0.13	0.4	V
Deglitch time (falling edge only)			150		μs



# **SWITCHING CHARACTERISTICS**

over recommended operating junction temperature range,  $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$ ,  $R_{ILIM} = 400 \Omega$  (unless otherwise noted)

	DADAMETED	7507.00	TI	PS2114	Α	TF				
	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
POWE	R SWITCH									
t <sub>r</sub>	Output rise time from an enable <sup>(1)</sup>	VI(IN1) = VI(IN2) = 5 V	$T_J = 25^{\circ}C$ , $C_L = 1 \mu F$ , $I_L = 500 \text{ mA}$ , See Figure 1(a)	0.5	1.0	1.5	1	1.8	3	ms
t <sub>f</sub>	Output fall time from a disable(1)	VI(IN1) = VI(IN2) = 5 V	$T_J = 25^{\circ}C$ , $C_L = 1 \mu F$ , $I_L = 500 \text{ mA}$ , See Figure 1(a)	0.35	0.5	0.7	0.5	1	2	ms
(1)		IN1 to IN2 transition, VI(IN1) = 3.3 V, VI(IN2) = 5 V	T <sub>J</sub> = 125°C, C <sub>L</sub> = 10 $\mu$ F, I <sub>L</sub> = 500 mA [Measure transition time		40	60		40	60	
t <sub>t</sub>	Transition time(1)	IN2 to IN1 transition, VI(IN1) = 5 V, VI(IN2) = 3.3 V	as 10–90% rise time or from 3.4 V to 4.8 V on VO(OUT)], See Figure 1(b)		40	60		40	60	μs
<sup>t</sup> PLH1	Turn-on propagation delay from enable <sup>(1)</sup>	VI(IN1) = VI(IN2) = 5 V Measured from enable to 10% of VO(OUT)	$T_J = 25^{\circ}C, C_L = 10 \mu F,$ $I_L = 500 \text{ mA},$ See Figure 1(a)		0.5			1		ms
<sup>t</sup> PHL1	Turn-off propagation delay from a disable <sup>(1)</sup>	VI(IN1) = VI(IN2) = 5 V, Measured from disable to 90% of VO(OUT)	$T_J = 25^{\circ}C$ , $C_L = 10 \mu F$ , $I_L = 500 \text{ mA}$ , See Figure 1(a)		3			5		ms
<sup>t</sup> PLH2	Switch-over rising propagation delay(1)	Logic 1 to Logic 0 transition on D1, VI(IN1) = 1.5 V, VI(IN2) = 5 V, VI(D0) = 0 V, Measured from D1 to 10% of VO(OUT)	$T_J = 25^{\circ}C$ , $C_L = 10 \mu F$ , $I_L = 500 \text{ mA}$ , See Figure 1(c)		40	100		40	100	μs
<sup>t</sup> PHL2	Switch-over falling propagation delay(1)	Logic 0 to Logic 1 transition on D1, VI(IN1) = 1.5V, VI(IN2) = 5V, VI(D0) = 0 V, Measured from D1 to 90% of VO(OUT)	$T_J = 25^{\circ}C$ , $C_L = 10 \mu F$ , $I_L = 500 \text{ mA}$ , See Figure 1(c)	2	3	10	2	5	10	ms

<sup>(1)</sup> Not tested in production.



# TRUTH TABLE

D1	D0	V <sub>I(IN2)</sub> > V <sub>I(IN1)</sub>	STAT	OUT(1)
0	0	X	Hi-Z	IN2
0	1	No	0	IN1
0	1	Yes	Hi-Z	IN2
1	0	Х	0	IN1
1	1	Х	0	Hi-Z

X = Don't care.

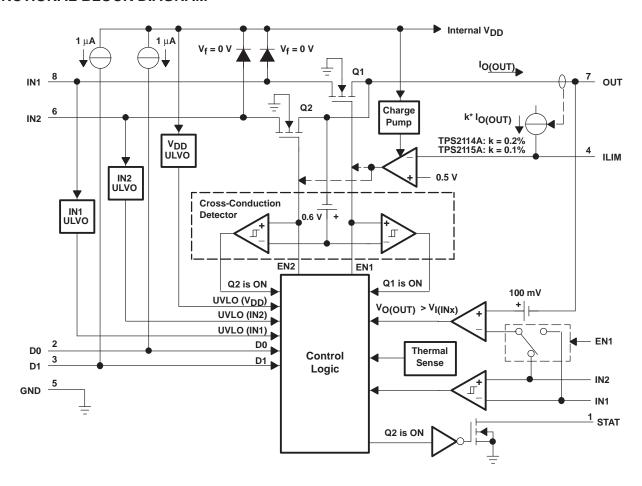
# **Terminal Functions**

TERMI	NAL		DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
D0	2	I	TTL- and CMOS-compatible input pins. Each pin has a 1-μA pull-up. The truth table shown above illustrates the
D1	3	1	functionality of D0 and D1.
GND	5	1	Ground
IN1	8	I	Primary power switch input. The IN1 switch can be enabled only if the IN1 supply is above the UVLO threshold and at least one supply exceeds the internal V <sub>DD</sub> UVLO.
IN2	6	I	Secondary power switch input. The IN2 switch can be enabled only if the IN2 supply is above the UVLO threshold and at least one supply exceeds the internal V <sub>DD</sub> UVLO.
ILIM	4	I	A resistor $R_{ILIM}$ from ILIM to GND sets the current limit $I_L$ to 250/ $R_{ILIM}$ and 500/ $R_{ILIM}$ for the TPS2114A and TPS2115A, respectively.
OUT	7	0	Power switch output
STAT	1	0	STAT is an open-drain output that is Hi-Z if the IN2 switch is ON. STAT pulls low if the IN1 switch is ON or if OUT is Hi-Z (i.e., EN is equal to logic 0).

<sup>(1)</sup>The under-voltage lockout circuit causes the output OUT to go Hi-Z if the selected power supply does not exceed the IN1/IN2 UVLO, or if neither of the supplies exceeds the internal VDD UVLO

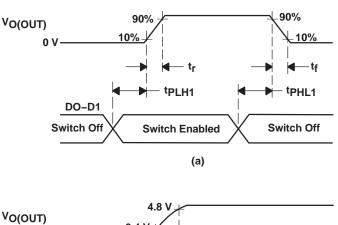


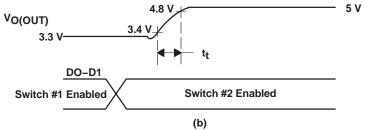
# **FUNCTIONAL BLOCK DIAGRAM**





# PARAMETER MEASUREMENT INFORMATION





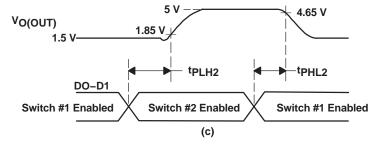


Figure 1. Propagation Delays and Transition Timing Waveforms



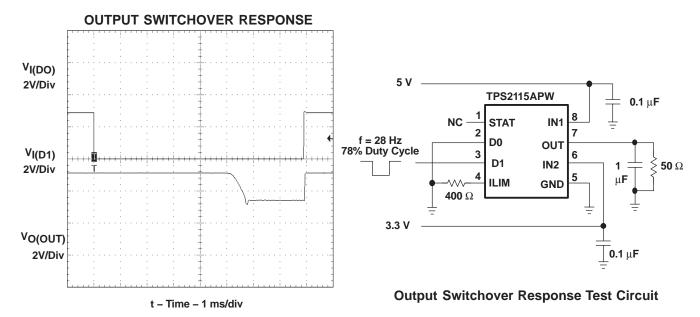


Figure 2

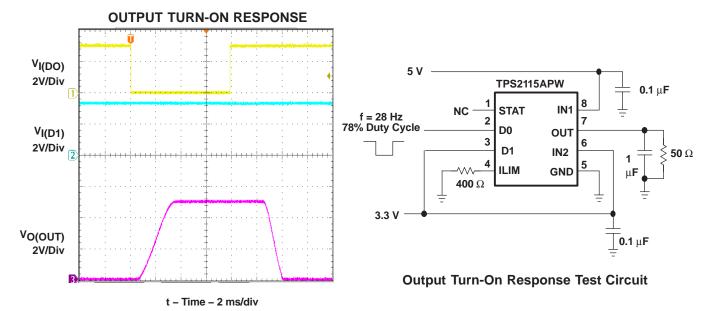
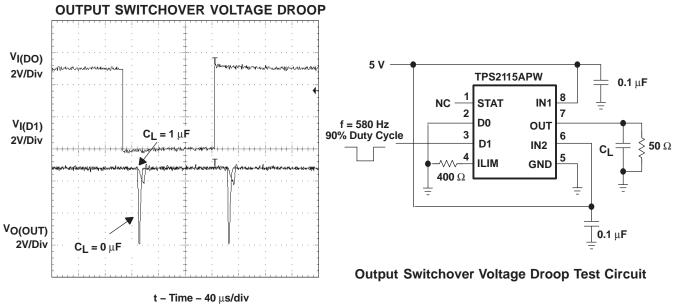


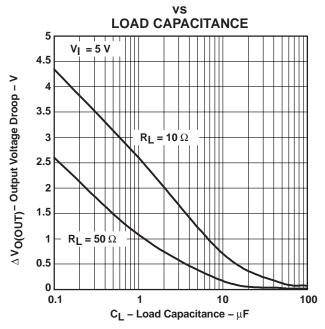
Figure 3

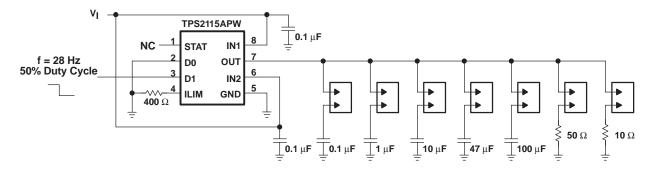






# **OUTPUT SWITCHOVER VOLTAGE DROOP**





**Output Switchover Voltage Droop Test Circuit** 

Figure 5

t - Time - 250 μs/div



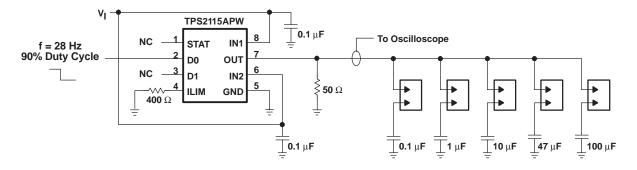
# **TYPICAL CHARACTERISTICS**

#### **AUTO SWITCHOVER VOLTAGE DROOP** $V_{I(IN1)}$ 2V/Div 5 V ● TPS2115A **0.1** μ**F** IN1 2 D0 **∨ V**оит OUT f = 220 Hz 3 20% Duty Cycle D1 IN2 $\lesssim$ 50 $\Omega$ 4 ILIM GND **0.1** μ**F** 400Ω ≷ V<sub>O(OUT)</sub> 2V/Div 75% less output voltage droop compared to TPS2115 **Auto Switchover Voltage Droop Test Circuit**

Figure 6



# INRUSH CURRENT VS LOAD CAPACITANCE 300 250 V<sub>I</sub> = 5 V V<sub>I</sub> = 3.3 V V<sub>I</sub> = 3.3 V

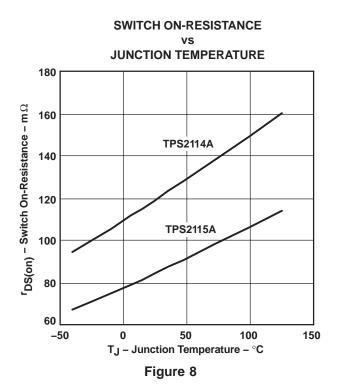


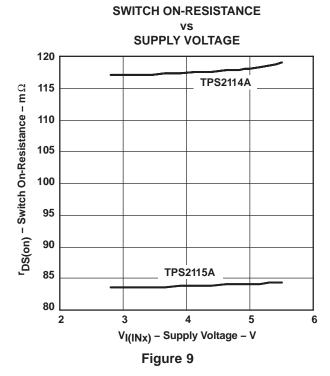
 $C_L$  – Load Capacitance –  $\mu F$ 

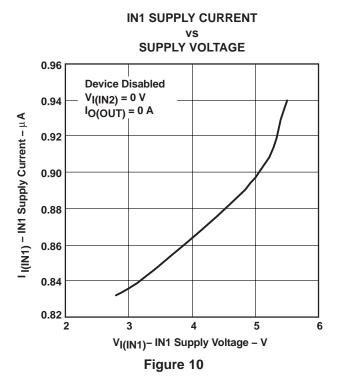
**Output Capacitor Inrush Current Test Circuit** 

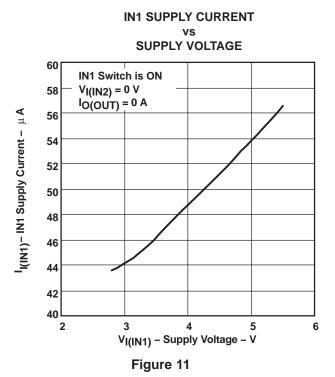
Figure 7



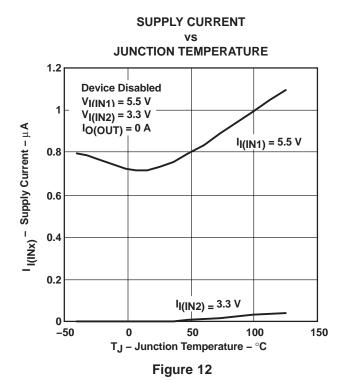


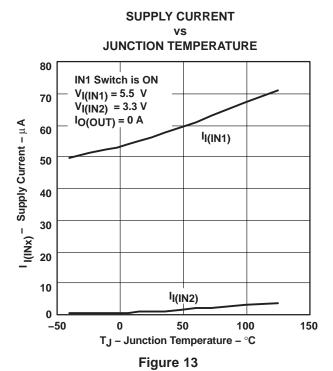














#### **APPLICATION INFORMATION**

Some applications have two energy sources, one of which should be used in preference to another. Figure 14 shows a circuit that will connect IN1 to OUT until the voltage at IN1 falls below a user-specified value. Once the voltage on IN1 falls below this value, the TPS2114A/5A will select the higher of the two supplies. This usually means that the TPS2114A/5A will swap to IN2.

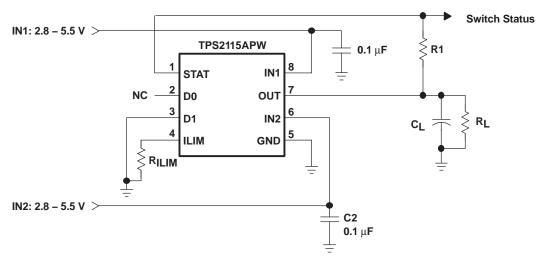


Figure 14. Auto-Selecting for a Dual Power Supply Application

In Figure 15, the multiplexer selects between two power supplies based upon the D1 logic signal. OUT connects to IN1 if D1 is logic 1; otherwise, OUT connects to IN2. The logic thresholds for the D1 terminal are compatible with both TTL and CMOS logic.

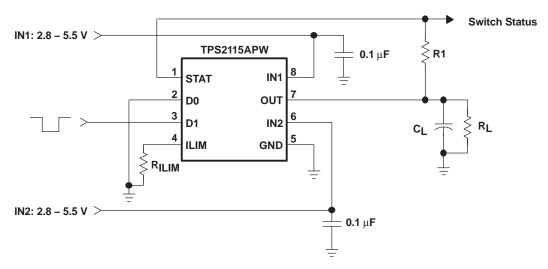


Figure 15. Manually Switching Power Sources



#### **DETAILED DESCRIPTION**

#### **AUTO-SWITCHING MODE**

D0 equal to logic 1 and D1 equal to logic 0 selects the auto-switching mode. In this mode, OUT connects to the higher of IN1 and IN2.

#### MANUAL SWITCHING MODE

D0 equal to logic 0 selects the manual-switching mode. In this mode, OUT connects to IN1 if D1 is equal to logic 1, otherwise OUT connects to IN2.

#### N-CHANNEL MOSFETs

Two internal high-side power MOSFETs implement a single-pole double-throw (SPDT) switch. Digital logic selects the IN1 switch, IN2 switch, or no switch (Hi-Z state). The MOSFETs have no parallel diodes so output-to-input current cannot flow when the FET is off. An integrated comparator prevents turn-on of a FET switch if the output voltage is greater than the input voltage.

#### **CROSS-CONDUCTION BLOCKING**

The switching circuitry ensures that both power switches will never conduct at the same time. A comparator monitors the gate-to-source voltage of each power FET and allows a FET to turn on only if the gate-to-source voltage of the other FET is below the turn-on threshold voltage.

#### **REVERSE-CONDUCTION BLOCKING**

When the TPS211xA switches from a higher-voltage supply to a lower-voltage supply, current can potentially flow back from the load capacitor into the lower-voltage supply. To minimize such reverse conduction, the TPS211xA will not connect a supply to the output until the output voltage has fallen to within 100 mV of the supply voltage. Once a supply has been connected to the output, it will remain connected regardless of output voltage.

#### **CHARGE PUMP**

The higher of supplies IN1 and IN2 powers the internal charge pump. The charge pump provides power to the current limit amplifier and allows the output FET gate voltage to be higher than the IN1 and IN2 supply voltages. A gate voltage that is higher than the source voltage is necessary to turn on the N-channel FET.

#### **CURRENT LIMITING**

A resistor  $R_{ILIM}$  from ILIM to GND sets the current limit to  $250/R_{ILIM}$  and  $500/R_{ILIM}$  for the TPS2114A and TPS2115A, respectively. Setting resistor  $R_{ILIM}$  equal to zero is not recommended as that disables current limiting.

# **OUTPUT VOLTAGE SLEW-RATE CONTROL**

The TPS2114A/5A slews the output voltage at a slow rate when OUT switches to IN1 or IN2 from the Hi-Z state (see *Truth Table*). A slow slew rate limits the inrush current into the load capacitor. High inrush currents can glitch the voltage bus and cause a system to hang up or reset. It can also cause reliability issues—like pit the connector power contacts, when hot-plugging a load such as a PCI card. The TPS2114A/5A slews the output voltage at a much faster rate when OUT switches between IN1 and IN2. The fast rate minimizes the output voltage droop and reduces the output voltage hold-up capacitance requirement.





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#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS2114APW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2114APWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2114APWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2114APWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2115ADRBR	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI
TPS2115ADRBT	PREVIEW	SON	DRB	8	250	TBD	Call TI	Call TI
TPS2115APW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2115APWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2115APWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2115APWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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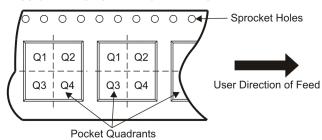
# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K	Dimension designed to accommodate the component thickness
V	/ Overall width of the carrier tape
ГР	Pitch between successive cavity centers

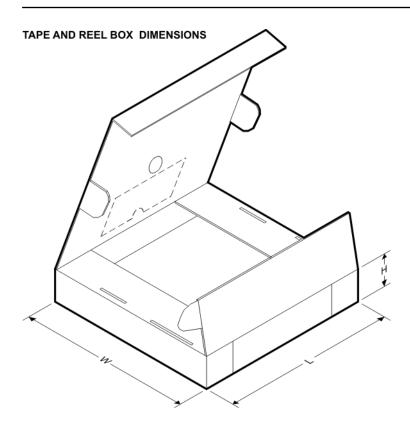
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2114APWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TPS2115APWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1





#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2114APWR	TSSOP	PW	8	2000	346.0	346.0	29.0
TPS2115APWR	TSSOP	PW	8	2000	346.0	346.0	29.0

# PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

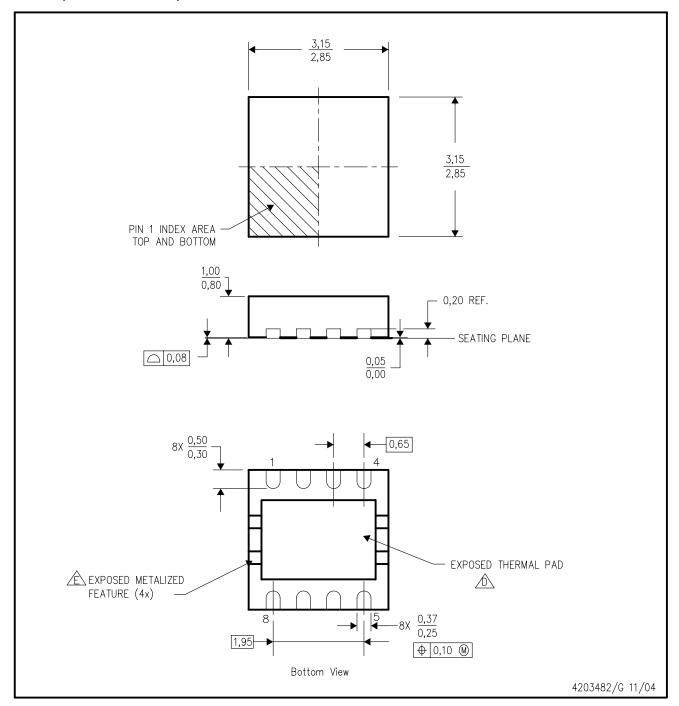
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

# DRB (S-PDSO-N8)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- Metalized features are supplier options and may not be on the package.



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